

MCT photoconductive detectors



P2748/P5274 series

Dewar type detector with high sensitivity and high-speed response in long wavelength range

Features

- ➔ **Choice of spectral response range (up to 25 μm)**
The band gap can be adjusted by controlling the composition ratio of HgTe and CdTe. Utilizing this fact, various types are available in different spectral characteristics.
- ➔ **Photoconductive element that decreases its resistance by input of infrared light**
- ➔ **Custom devices available**
Custom devices not listed in this catalog are also available with different spectral response, active area sizes and number of elements.
Glass dewar type not requiring repumping is also provided.

Applications

- ➔ FTIR
- ➔ Infrared spectrophotometers
- ➔ Thermal imaging
- ➔ Remote sensing
- ➔ CO₂ laser detection

Options

- ➔ Valve operator **A3515**
- ➔ Amplifiers for dewar type MCT photoconductive detector **C5185-02**

Structure / Absolute maximum ratings

| Type no. | Dimensional outline/ Window material | Package | Cooling | Photosensitive area (mm) | Nitrogen hold time Min. (h) | Absolute maximum ratings | | |
|----------|---|--------------------------|-----------------|---------------------------------|---------------------------------------|--------------------------------|---------------------------------------|-------------------------------------|
| | | | | | | Allowable bias current (mA) | Operating temperature Topr (°C) | Storage temperature Tstg (°C) |
| P2748-40 | (1)/ZnS | Side-on type metal dewar | Liquid nitrogen | 1 × 1 | 12 | 40 | -40 to +60 | -55 to +60 |
| P2748-41 | (2)/ZnS | Head-on type metal dewar | | 1 × 1 | | 40 | | |
| P2748-42 | (1)/ZnS | Side-on type metal dewar | | 0.25 × 0.25 | | 20 | | |
| P5274 | (1)/ZnSe | | | 1 × 1 | | 40 | | |
| P5274-01 | (1)/KRS-5 | | | 1 × 1 | | 20 | | |

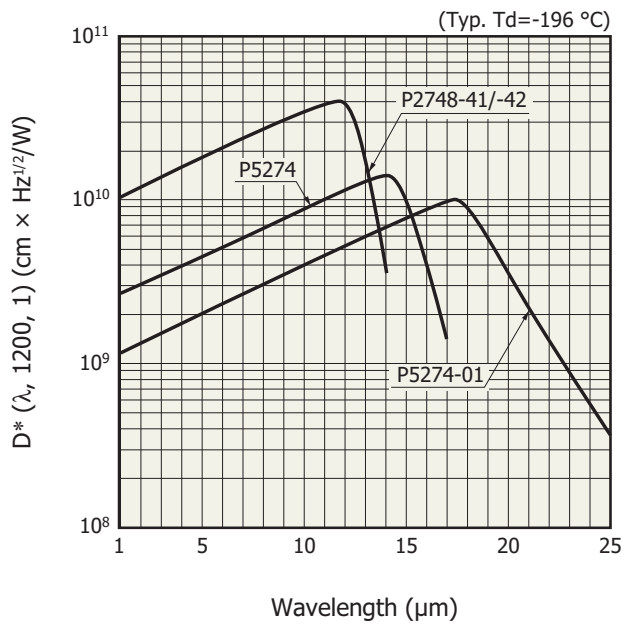
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

Electrical and optical characteristics (Typ. unless otherwise noted)

| Type no. | Measurement condition Element temperature Td | Peak sensitivity wavelength λ_p | Cutoff wavelength λ_c | Photo-sensitivity*1 S $\lambda = \lambda_p$ | D* (500, 1200, 1) | | D* (λ_p , 1200, 1) | NEP $\lambda = \lambda_p$ | Rise time tr 0 to 63% | Dark resistance Rd |
|----------|--|--|----------------------------------|---|--|--|--|------------------------------|-----------------------------|-----------------------|
| | (°C) | (μm) | (μm) | (V/W) | Min. ($\text{cm} \cdot \text{Hz}^{1/2}/\text{W}$) | Typ. ($\text{cm} \cdot \text{Hz}^{1/2}/\text{W}$) | ($\text{cm} \cdot \text{Hz}^{1/2}/\text{W}$) | (W/Hz ^{1/2}) | (μs) | (Ω) |
| P2748-40 | -196 | 12 | 14 | 1000 | 1×10^{10} | 2×10^{10} | 4.0×10^{10} | 2.5×10^{-12} | 0.6 | 40 |
| P2748-41 | | | | 1000 | | | | 2.5×10^{-12} | | |
| P2748-42 | | | | 10000 | | | | 6.3×10^{-12} | | |
| P5274 | | 14 | 17 | 500 | 2×10^9 | 1×10^{10} | 1.5×10^{10} | 6.7×10^{-12} | 0.6 | 30 |
| P5274-01 | | 17 | 22 | 250 | 1×10^9 | 5×10^9 | 1.0×10^{10} | 1.0×10^{-11} | 0.4 | 100 |

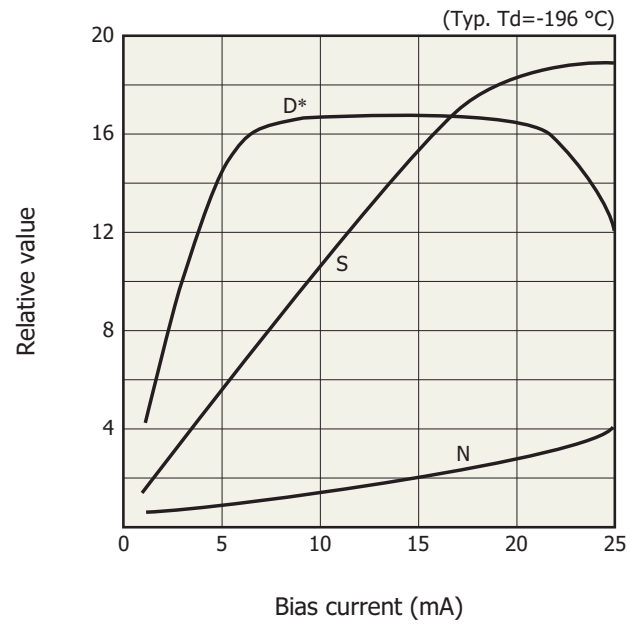
*1: Photosensitivity changes with the bias current. The values in the above table are measured with the optimum bias current.

Spectral response



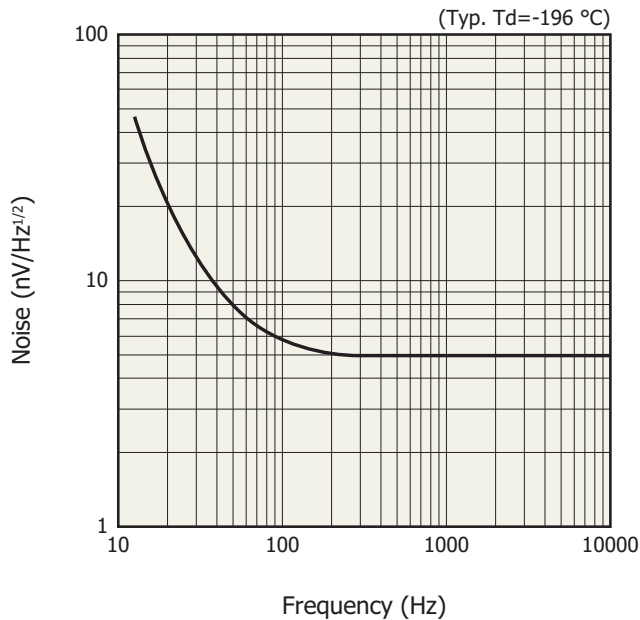
Spectral response can be shifted upon request.

S/N vs. bias current

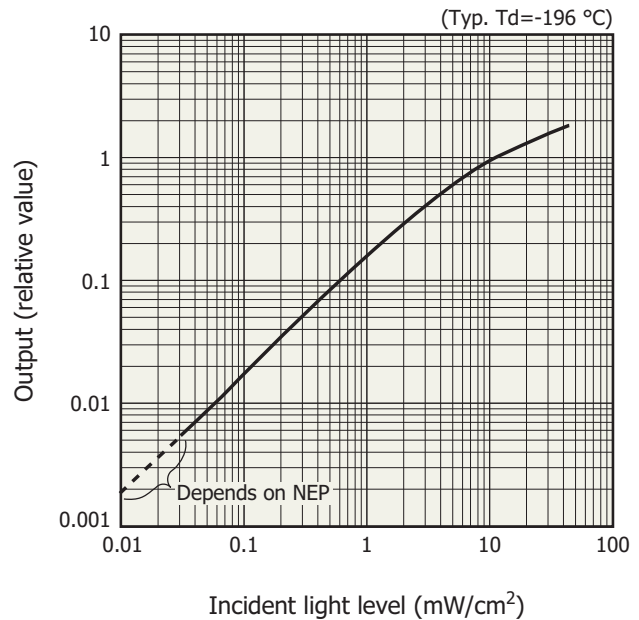


The detector must be operated in a range where the D^* becomes Max.

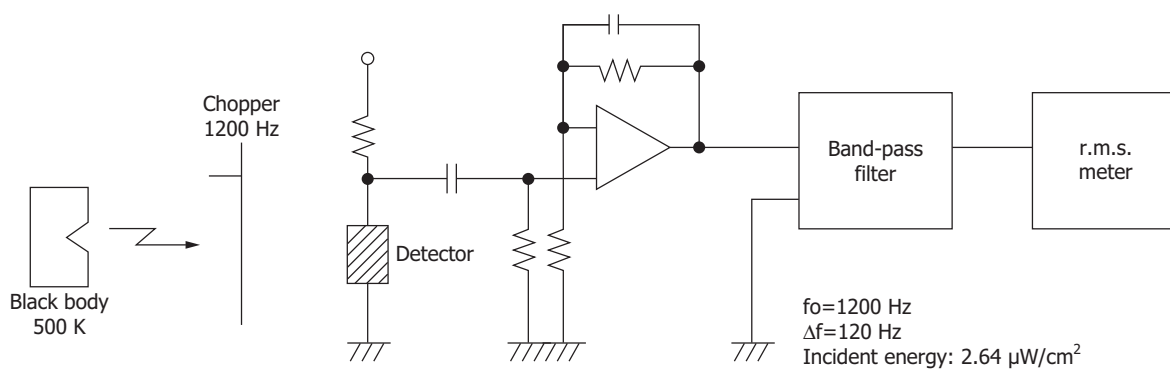
Noise vs. frequency



Linearity (P2748-40)



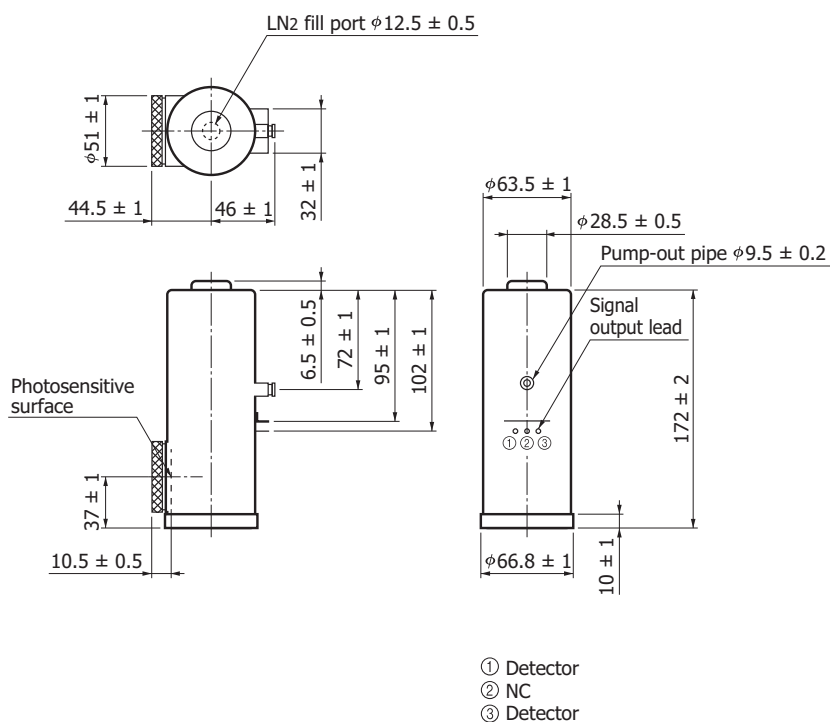
Measurement circuit



KIRD0007EB

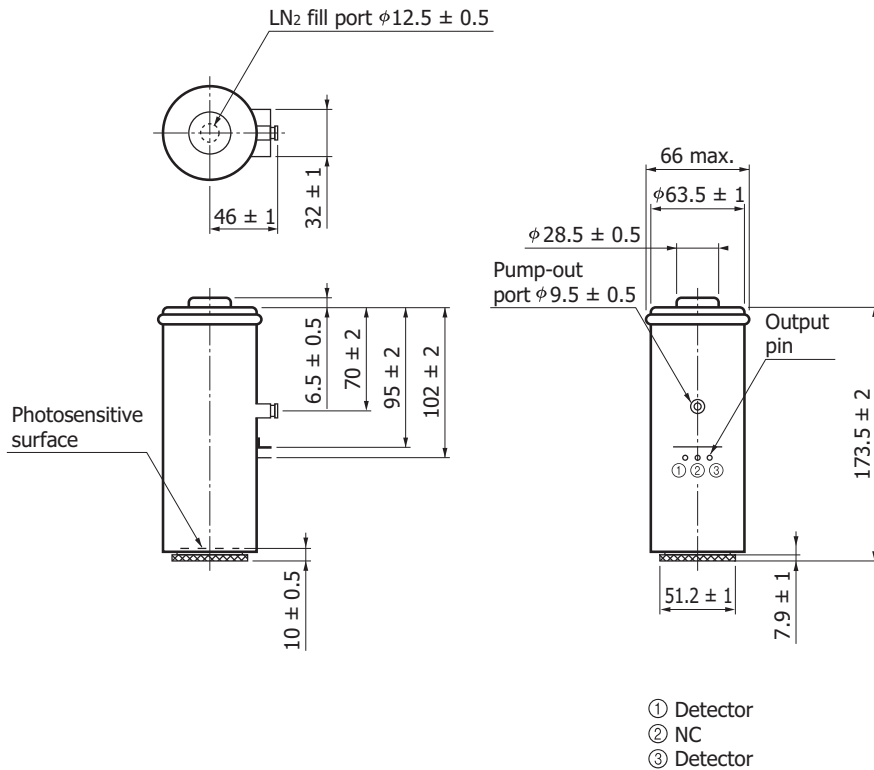
Dimensional outline (unit: mm)

(1) P2748-40/-42, P5274 series



KIRDA0131EE

(2) P2748-41



KIRDA0129EC

Information described in this material is current as of November, 2012.

Product specifications are subject to change without prior notice due to improvements or other reasons. Before assembly into final products, please contact us for the delivery specification sheet to check the latest information.

Type numbers of products listed in the delivery specification sheets or supplied as samples may have a suffix "(X)" which means preliminary specifications or a suffix "(Z)" which means developmental specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

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